New EDELWEISS sub-GeV Results

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A wide playground



Edelweiss sub-GeV program

• Current and future projects



- For event by event NR ID down to 1 GeV/c² and reach 10^{-43} cm² σ_{phonon} = 10 eV and σ_{ion} = 20 eVee
- Ionization resolution is key to particle identification + surface rejection: Cold HEMT preamp + low capacitance wiring (joint development with Ricochet)



- Reducing detector mass is crucial to reach these goals: EDELWEISS-Surf [PRD 99 082013 (2019)] 33 g Ge bolometer.
- Applying HV to amplify signal, lower threshold and separate NR /ER: Electron-DM results [PRL 125, 141401 (2020)] 78 V applied onto 33 g Ge bolometer.
- Lowering the Impact of Background using new TES sensor on 200g Ge bolometer operated at 66V. This presentation.



Amplifying signal: Neganov-Luke-Trofimov effect

• Amplification of heat signal due to Np electrons drifting in electric field



$$E_{heat} = E_{recoil} + \frac{E_{Luke}}{\epsilon} = E_{recoil} + \frac{N_p}{\Delta V}$$
$$E_{heat} = E_{recoil} (1 + \frac{\Delta V}{\epsilon}) \text{ particle-ID dependent}$$

- Amplification proportional to ionization signal and to applied bias
 - Loss of discrimination as heat is dominated by ionization signal
 - Resolution gain by a factor (1+V/3) for e⁻ signals



EDELWEISS Sub-GeV two modes



Low-voltage objectives are part of a common effort with the Ricochet collaboration, dedicated to studying CENNS at reactors supported by the ERC-CENNS Starting Grant (2019-2024)



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Advance toward Sub-GeV: sub-electron resolution

- Detector RED30: 33g Ge operated at 78V, σ = 1.6x eV (0.54 pair)
- Best Ge sensitivity for DM-e and DP down to 1 eV
- Limited by heat-only background: understanding + control of this background (also observed in other cryogenic detectors)





EDELWEISS NbSi TES

- 200g Ge bolometer
- NbSi TES thermal sensor lithographed on top surface.
 100 nm thick, 20 mm diameter spiral, 17% of top surface, split in two halves (inner and outer circles).
- Flat surface electrodes: lithographed Al grid (500 µm pitch, 4% coverage) to reduce phonon trapping
- No side electrodes on this detector, stable operation at 66V bias (mitigation of risk of leakage at HV)
- Part of the longest LSM cool-down: December 2018 July 2020
- 4 eVee resolution at 66V + reduced HO background: ideal for Midgal searches



The Migdal effect in a nutshell

- Nuclear recoil is produced simultaneously with an additional electron recoil, with up to few 100 eV energy.
- For WIMP mass << few GeV/c², electron energy very large compare to nuclear recoil (and not affected by quenching) $\frac{m_{\chi} = 50 \text{ MeV}; \sigma_p^{\text{SI}} = 10^{-30} \text{ cm}^2}{10^9} \times \frac{10^9 \text{ cm}$
- Calculation in Ge (lbe et al arxiv:1707.07258) reliable for n = 3 shell electrons (only shell considered here).
- Migdal electron energy = 35 eV in Ge (Ideal target of search for NbSi209 with $\sigma = 4 \text{ eVee}$)





EDELWEISS-III Setup

- LSM: Deepest site in Europe 4800 m.w.e., 5 μ/m²/day
- Clean room + deradonized air
 Radon monitoring down to few mBq/m³
- Active muon veto (>98% coverage) on mobile shield
- External (50 cm) + internal polyethylene shielding Thermal neutron monitoring with ³He detector
- Lead shielding (20 cm, including 2 cm Roman lead)
- Selection of radiopure material





Cryostat can host up to 40 kg detector at 18 mK

Performance of the EDELWEISS-III experiment for direct dark matter searches

[JINST 12 (2017) P08010]

Analysis: Calibration

- Calibration from K, L, M, ⁷¹Ge decay line.
- Baseline resolution 100 eV on total energy, i.e. 4 eVee for electron recoils at 66V
- Quality cut to reject spurious events.
- Fraction of events with full charge collection and no extra signal from out-of-equilibrium phonons: 64%



Analysis: Efficiency

- Full pulse simulation: Efficiency determined from injection of actual 10.37 keV events, scaled to desired energy, at random times in entire search data
- Conservatively only consider efficiency for events with full charge collection and no out-of-equilibrium phonons (64%) - green "Bank cut"
- Trigger on heat channel using optimal filter (blue)
- To reduce as much as possible HO background, require > 400 eVee signal on electrodes (brown), compared to σ = 200 eVee. Aggressive, but well-understood cut.
- Loose cuts on chi2 pulse fit (ionization and heat) + equal signal on both NbSi film halves: small effect on efficiency.



Analysis: strategy

- Poisson upper limit assuming all events are DM candidates, no background subtraction
- Dataset divided in half, 1 over 2 hours blinded
- The other half use to set analysis cut and region of interest
- each set represent 28 days of data



Analysis: limit extraction

- Region of interest → maximize ratio ^t/₅ signal over background in non-blind ^c/_{010⁴} sample
- Using these fixed ROI, 90%CL Poisson upper limit on rate in blind sample
- Signal corrected for Earth shielding effect (ESE): at too high cross-section, the DM flux cannot reach the detector.
- For a given mass, large ESE effects can change both DM spectrum shape and rate (right)



Analysis: Results

- Earth shielding lower the mass range sensitivity
- Strong effect starting at 50 MeV/c²
- MC toys used to probe statistical stability of the results.



Analysis: Results

- First result below 50 MeV/c²
- Extend the reach of WIMP search down to 32 MeV/c²
- Improvement relative to previous EDELWEISS results due to deep underground site, improved resolution (with NTL amplification) and improved HO background in new NbSi detector.
- Good sign for the coming EDELWEISS-SubGeV program



Future: CRYOSEL



- ANR CRYOSEL: 40g Ge detector, σ_{phonon} = 20 eV, sustaining 200 V bias
 SSED detector able to detect athermal phonon emission of individual
- SSED detector able to detect athermal phonon emission of individual charges passing through the high-field region in front of it (red dot). Drastic rejection of HO events.
- Expect many orders of magnitude improvement compared to present-day sensitivity, even with 1 kg.d exposure







Conclusion

- EDELWEISS-SubGeV:
 - event-by-event rejection at lower mass, exploring both low-bias mode (in synergy with Ricochet) and high-bias mode (ANR CRYOSEL)
 - Progress (and new DM limits) already achieved (17.3 eV phonon resolution, 0.53 e-h+ resolution at 78V)
 - ANR CRYOSEL to master HO background in HV detector and fully open mass range from 1 eV/c² to 1 GeV/c²
- New result with 200g Ge with NbSi Transition Edge Sensor:
 - First EDELWEISS limits using athermal phonon sensor
 - 4 eVee resolution at 66V
 - Reduced background of HO events
 - First Migdal WIMP limits at 32 MeV/c²

Backups

Spectra comparison after cut on E_ion (LV)



Toward 20 eVee ionization resolution

- Transition from JFET to HEMT
 [Phipps:1611.09712, and arXiv:1909.02879]
- Lower intrinsic noise + reduce cabling capacitance by working at 1K or 4K
- Data driven HEMT models show that the goal of 20 eV_{ee} is reachable with ~20 pF total input impedance
- Ongoing HEMT characterizations



- HEMT-based preamp tests end of 2019
- Cryogenics + cabling challenges ahead
- Work done in synergy with the Ricochet-CryoCube collaboration





Optimization of 33g FID design: large fiducial volume & low capacitance